Supplementary data to:

Theoretical study on the origin of activity for oxygen reduction reaction of metal doped two-dimensional boron nitride materials

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Catalysts	*O2	*OOH	*0	*OH
BN				
BN	6-€0-€0-€0-€	~ € 0-80-80-80-90-9	0-40-40 *0-40-40	€ 0-60-60-60-60-60-
Mg–BN				
Mg–BN		s ceitid enco	centres	
Al–BN				
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Sc–BN				
Sc–BN	• •	*	0000000	* ********
Ti–BN				
Ti–BN	• • •			é ≎ €₽₽≈∞ •
V–BN				
V–BN	~~ c≪*****	certition and		€ 0 @1000000 0000

Table S1. Optimized adsorption configurations (top and side views) of key oxygenated intermediates involved in the ORR on M–BN materials (red: oxygen atoms; white: hydrogen atoms; blue: nitrogen atoms).

Cr–BN				
Cr–BN		······································		
Mn–BN				
Mn–BN	0404040-00+		0.40.40.40 +0.+	
Fe–BN				
Fe–BN	0404040-00 0		C 4 2 4 2 4 0 4 0 4 0 4 0	i and the second
Co–BN				
Co–BN			C 4 2 4 2 4 0 4 0 4 0 4 0	
Ni–BN				
Ni–BN				
Cu–BN				
Cu–BN				and the second
Zn–BN				
Zn–BN		s colonno		



Figure S1. The free energy diagram at the onset potentials for Cu–BN, Zn–BN, Al–BN and BN materials (a) the 2e⁻ mechanism, (b) the 4e⁻ mechanism.





Figure S2. The local density of states for M–BN materials (a) pristine state of BN,(b) Mg–BN, (c) Al–BN, (d) Sc–BN, (e) Ti–BN, (f) V–BN, (g) Cr–BN,(h) Mn–BN, (i) Fe–BN, (j) Co–BN, (k) Ni–BN, (l) Cu–BN, (m) Zn–BN.





Figure S3. The highest occupied molecular orbital (HOMO) of (a) Mg–BN, (b) Al–BN, (c) Sc–BN, (d) Ti–BN, (e) V–BN, (f) Cr–BN, (g) Mn–BN, (h) Fe–BN, (i) Co–BN, (j) Ni–BN, (k) Cu–BN, (l) Zn–BN



Figure S4. The pathways of the 2e⁻ mechanism for Cu–BN materials.



Figure S5. The pathways of the 4e⁻ mechanism for Co–BN materials.